TinyLogic HS Inverter

NC7S04

Description

The NC7S04 is a single high performance CMOS Inverter. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad V_{CC} range. ESD protection diodes inherently guard both input and output with respect to the V_{CC} and GND rails. Three stages of gain between input and output assures high noise immunity and reduced sensitivity to input edge rate.

Features

- Space-Saving SC-74A and SC-88A 5-Lead Package
- Ultra−Small MicroPak™ Leadless Package
- High Speed: $t_{PD} = 3$ ns Typ
- Low Quiescent Power: I_{CC}< 1 μA
- Balanced Output Drive: 2 mA I_{OL}, -2 mA I_{OH}
- Broad V_{CC} Operating Range: 2 V 6 V
- Balanced Propagation Delays
- Specified for 3 V Operation
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol



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SIP6 CASE 127EB



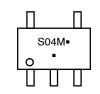


SC-74A **CASE 318BQ**





SC-88A CASE 419A-02



NC7S04/D

AA, 7S04, S04 = Specific Device Code

ΚK = 2-Digit Lot Run Traceability Code XY = 2-Digit Date Code Format

Ζ = Assembly Plant Code

М = Date Code*

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

NC7S04

Pin Configurations

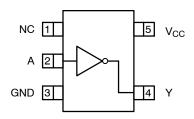


Figure 2. SC-88A and SC-74A (Top View)

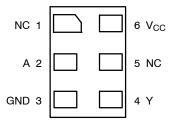


Figure 3. MicroPak (Top Through View)

PIN DESCRIPTIONS

| Name | Description |
|------|-------------|
| Α | Input |
| Y | Output |
| NC | No Connect |

FUNCTION TABLE $(Y = \overline{A})$

| Input | Output |
|-------|--------|
| Α | Y |
| L | Н |
| Н | L |

H = HIGH Logic Level L = LOW Logic Level

NC7S04

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | | Min | Max | Unit |
|-------------------------------------|---|------------------------------------|------|-----------------------|------|
| V _{CC} | Supply Voltage | | -0.5 | 6.5 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < 0 V | - | -20 | mA |
| | | V _{IN} > V _{CC} | - | +20 | |
| V _{IN} | DC Input Voltage | | -0.5 | V _{CC} + 0.5 | V |
| I _{OK} | DC Output Diode Current V _{OUT} < 0 V | | - | -20 | mA |
| | | V _{OUT} > V _{CC} | - | +20 | |
| V _{OUT} | DC Output Voltage | | -0.5 | V _{CC} + 0.5 | V |
| I _{OUT} | DC Output Source or Sink Current | | - | ±12.5 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current per Output Pin | | - | ±25 | mA |
| T _{STG} | Storage Temperature | | -65 | +150 | °C |
| TJ | Junction Temperature | | - | +150 | °C |
| TL | Lead Temperature (Soldering, 10 Seconds) | | - | +260 | °C |
| P_{D} | Power Dissipation in Still Air | SC-74A | - | 390 | mW |
| | | SC-88A | - | 332 | 7 |
| | | MicroPak-6 | - | 812 | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------------------|---------------------------|--------------------------|-----|-----------------|------|
| V _{CC} | Supply Voltage | | 2.0 | 6.0 | V |
| V _{IN} | Input Voltage | | 0 | V _{CC} | V |
| V _{OUT} | Output Voltage | | 0 | V _{CC} | V |
| T _A | Operating Temperature | | -40 | +85 | °C |
| t _r , t _f | Input Rise and Fall Times | V _{CC} at 2.0 V | 0 | 20 | ns |
| | | V _{CC} at 3.0 V | 0 | 20 | |
| | | V _{CC} at 4.5 V | 0 | 10 | |
| | | V _{CC} at 6.0 V | 0 | 5 | |
| $\theta_{\sf JA}$ | Thermal Resistance | SC-74A | - | 320 | °C/W |
| | | SC-88A | - | 377 | |
| | | MicroPak-6 | - | 154 | |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

^{1.} Unused inputs must be held HIGH or LOW. They may not float.

NC7S04

DC ELECTICAL CHARACTERISTICS

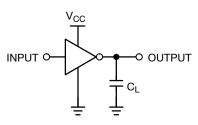
| | | | | - | Γ _A = +25°C | ; | T _A = -40 | to +85°C | |
|-----------------|---------------------------|--------------------------|--|------------------------------|--------------------------|------------------------------|------------------------------|------------------------------|------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Min | Тур | Max | Min | Max | Unit |
| V _{IH} | HIGH Level Input Voltage | 2.0 3.0 - 6.0 | | 1.50 0.7 V _{CC} | - - | - - | 1.50 0.7 V _{CC} | - - | V |
| V _{IL} | LOW Level Input Voltage | 2.0 3.0 - 6.0 | | - - | - - | 0.50 0.3 V _{CC} | - - | 0.50 0.3 V _{CC} | V |
| V _{OH} | HIGH Level Output Voltage | 2.0 3.0 4.5 6.0 | $I_{OH} = -20 \mu A$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ | 1.90 2.90 4.40 5.90 | 2.0 3.0 4.5 6.0 | - - - - | 1.90 2.90 4.40 5.90 | - - - - | V |
| | | 3.0 4.5 6.0 | $\begin{aligned} &V_{IN} = \ V_{IH} \text{ or } V_{IL} \\ &I_{OH} = -1.3 \text{ mA} \\ &I_{OH} = -2.0 \text{ mA} \\ &I_{OH} = -2.6 \text{ mA} \end{aligned}$ | 2.68 4.18 5.68 | 2.85 4.35 5.85 | - - - | 2.63 4.13 5.63 | - - - | V |
| V _{OL} | LOW Level Output Voltage | 2.0 3.0 4.5 6.0 | $I_{OL} = 20 \mu A$ $V_{IN} = V_{IH} \text{ or } V_{IL}$ | - - - - | 0.0 0.0 0.0 0.0 | 0.10 0.10 0.10 0.10 | - - - - | 0.10 0.10 0.10 0.10 | V |
| | | 3.0 4.5 6.0 | $\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OL} = 1.3 \text{ mA} \\ &I_{OL} = 2.0 \text{ mA} \\ &I_{OL} = 2.6 \text{ mA} \end{aligned}$ | - - - | 0.1 0.1 0.1 | 0.26 0.26 0.26 | - - - | 0.33 0.33 0.33 | V |
| I _{IN} | Input Leakage Current | 6.0 | V _{IN} = V _{CC} , GND | - | - | ±0.1 | - | ±1.0 | μА |
| I _{CC} | Quiescent Supply Current | 6.0 | V _{IN} = V _{CC} , GND | - | - | 1.0 | _ | 10.0 | μΑ |

AC ELECTRICAL CHARACTERISTICS

| | | | | - | Γ _A = +25°0 | • | T _A = -40 | to +85°C | |
|-------------------------------------|--|--------------------------|------------------------|-------------|-----------------------------|-------------------------------|----------------------|-------------------------------|------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Min | Тур | Max | Min | Max | Unit |
| t _{PLH} , t _{PHL} | Propagation Delay (Figure 4, 6) | 5.0 | C _L = 15 pF | = | 3.0 | 15.0 | - | - | ns |
| | | 2.0 3.0 4.5 6.0 | C _L = 50 pF | - - - | 18.0 10.0 7.0 6.0 | 100.0 27.0 20.0 17.0 | - - - | 125.0 35.0 25.0 21.0 | ns |
| t _{TLH} , t _{THL} | Output Transition Time | 5.0 | C _L = 15 pF | - | 3.0 | 10.0 | - | - | ns |
| | (Figure 4, 6) | 2.0 3.0 4.5 6.0 | C _L = 50 pF | - - - | 25.0 16.0 11.0 9.0 | 125.0 35.0 25.0 21.0 | - - - | 155.0 45.0 31.0 26.0 | ns |
| C _{IN} | Input Capacitance (Figure 4, 6) | Open | | _ | 2.0 | 10.0 | - | 10.0 | pF |
| C _{PD} | Power Dissipation Capacitance (Figure 5) | 5.0 | (Note 2) | - | 6.0 | - | - | - | pF |

^{2.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz, $t_{\rm W}$ = 500 ns

Figure 4. AC Test Circuit

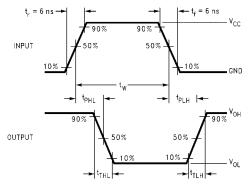
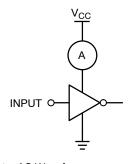


Figure 6. AC Waveforms



Input = AC Waveforms;

PRR = Variable; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit

DEVICE ORDERING INFORMATION

| Device | Top Mark | Packages | Shipping [†] |
|-----------|----------|----------------|-----------------------|
| NC7S04M5X | 7S04 | SC-74A | 3000 / Tape & Reel |
| NC7S04P5X | S04 | SC-88A | 3000 / Tape & Reel |
| NC7S04L6X | AA | SIP6, MicroPak | 5000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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DATE 31 AUG 2016



NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
 4. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

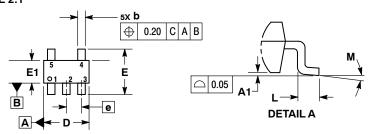
 - OTHER LINE IN THE MARK CODE LAYOUT.

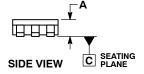
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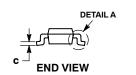
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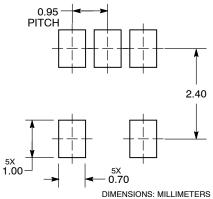
DATE 18 JAN 2018







RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
 Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE
 MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

| | MILLIMETERS | | | |
|-----|-------------|------|--|--|
| DIM | MIN | MAX | | |
| Α | 0.90 | 1.10 | | |
| A1 | 0.01 | 0.10 | | |
| b | 0.25 | 0.50 | | |
| С | 0.10 | 0.26 | | |
| D | 2.85 | 3.15 | | |
| E | 2.50 | 3.00 | | |
| E1 | 1.35 | 1.65 | | |
| е | 0.95 BSC | | | |
| L | 0.20 | 0.60 | | |
| М | 0 ° | 10° | | |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

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SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE L**

DATE 17 JAN 2013



- TES:
 DIMENSIONING AND TOLERANCING
 PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 419A-01 OBSOLETE. NEW STANDARD 3.
- 419A-02.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | INC | HES | MILLIN | IETERS |
|-----|-----------|-------|----------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.071 | 0.087 | 1.80 | 2.20 |
| В | 0.045 | 0.053 | 1.15 | 1.35 |
| С | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 | 0.30 |
| G | 0.026 | BSC | 0.65 BSC | |
| Н | | 0.004 | | 0.10 |
| J | 0.004 | 0.010 | 0.10 | 0.25 |
| K | 0.004 | 0.012 | 0.10 | 0.30 |
| N | 0.008 REF | | 0.20 | REF |
| S | 0.079 | 0.087 | 2.00 | 2.20 |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



0.50 0.0197 0.65 0.025 0.65 0.025 0.40 0.0157 1.9 mm 0.0748 SCALE 20:1

SOLDER FOOTPRINT

| STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR | STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE | STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1 | STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2 | STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4 |
|--|--|--|--|--|
| | | | | |

| 5. COLLECTOR | 5. CATHODE | 5. CATHODE I | 5. GATE 2 | 5. CATHODE 4 |
|--|--|--|--|---|
| STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE 1 | STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR | STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER | STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE | Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment. |

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